NSN 5962-01-319-0513

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View Online at https://aerobasegroup.com/nsn/5962-01-319-0513

Overall Length:

1.280 inches

Overall Height:

0.355 inches

Overall Width:

0.620 inches

Body Length:

1.280 inches

Body Width:

0.550 inches

Body Height:

0.210 inches

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and burn in and erasable and high performance and high speed and low power and programmable

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

11 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Rom

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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